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NTST40100CTG. NTSB40100CT-1G, NTSB40100CTG, NTSJ40100CTG

Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low $V_F = 0.38$ V at $I_F = 5$ A

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

Typical Applications

- ENTATIVEFOR Switching Power Supplies including Notebook / Netbook Adapters, EASECONTA ATX and Flat Panel Display
- High Frequency and DC-DC Converter
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



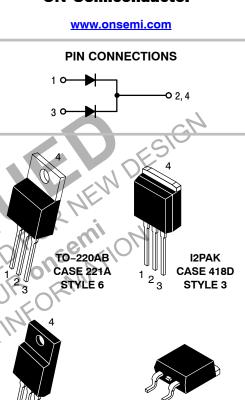
D2PAK

CASE 418B

TO-220FP

CASE 221AH

See detailed ordering and shipping information on page 5 of this data sheet.



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MAXIMUM RATINGS

Rating			Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (Rated V _R , T _C = 120°C)	Per device Per diode	I _{F(AV)}	40 20	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, T_C = 125°C)	Per device Per diode	I _{FRM}	60 30	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	250	A
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality EN DE should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

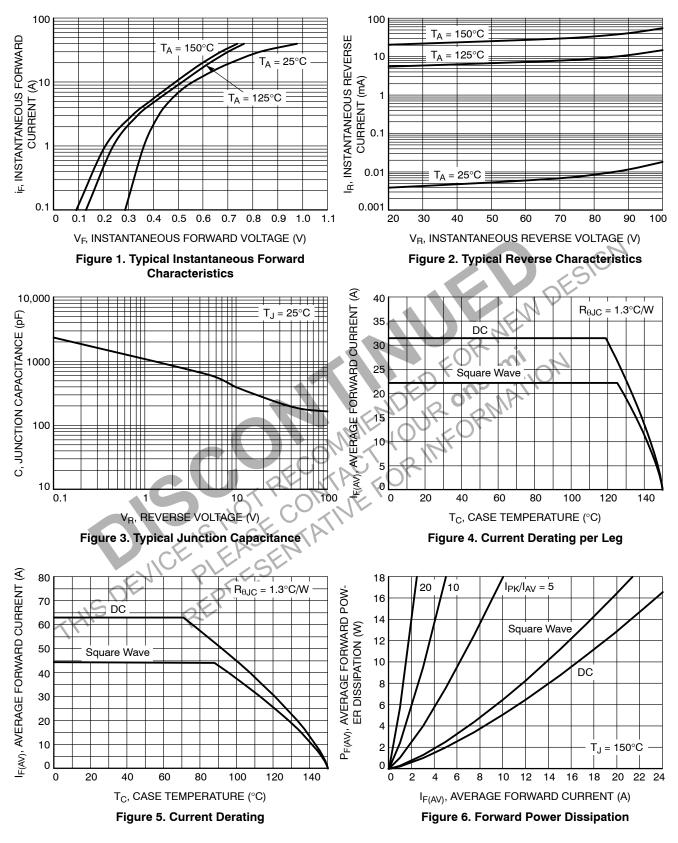
Rating	Symbol	NTST40100CTG, NTSB40100CT-1G	NTSB40100CTG	NTSJ40100CTG	Unit		
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	${\sf R}_{ heta { m JC}} {\sf R}_{ heta { m JA}}$	1.3 70	0.79 46.3	4.0 105	°C/W °C/W		
ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)							

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted

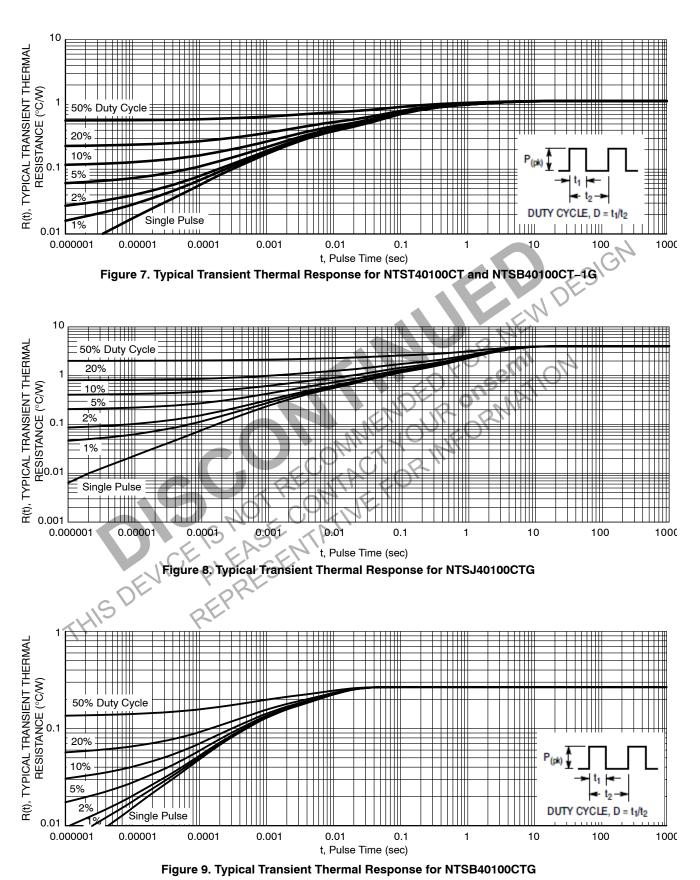
Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1)	٧F			V
(I _F = 5 A, T _J = 25°C)		0.46	-	
$(I_{\rm F} = 10 \text{ Å}, T_{\rm J} = 25^{\circ}{\rm C})$		0.56	-	
$(I_F = 20 \text{ A}, T_J = 25^{\circ}\text{C})$		0.71	0.80	
		0.41		
$(I_F = 5 A, T_J = 125^{\circ}C)$ $(I_F = 10 A, T_J = 125^{\circ}C)$		0.41	_	
$(l_{\rm F} = 20 {\rm A}, T_{\rm J} = 125{\rm °C})$		0.63	0.68	
Maximum Instantaneous Reverse Current (Note 1)	I _B			
$(V_{\rm R} = 70 \text{V}, T_{\rm y} = 25^{\circ} \text{C})$		12		μΑ
$(V_{\rm R} = 70 \text{ V}, \text{T}_{\rm J} = 125^{\circ}\text{C})$		8.0		mΑ
(Rated dc Voltage, $T_J = 25^{\circ}$ C)		20	1000	μA
(Rated dc Voltage, T _J = 125°C)		20	45	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle $\leq 2.0\%$



TYPICAL CHARACTERISTICS



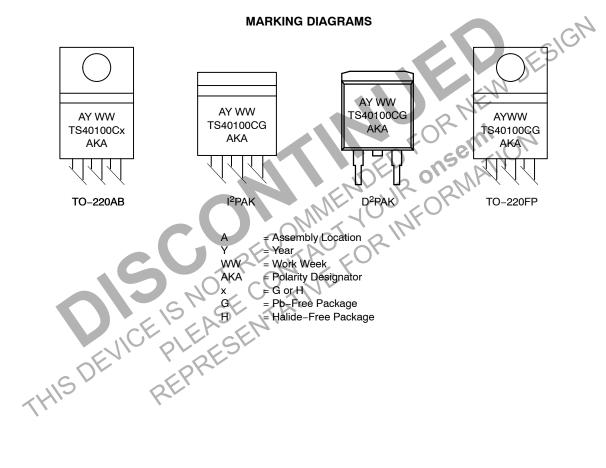
TYPICAL CHARACTERISITICS

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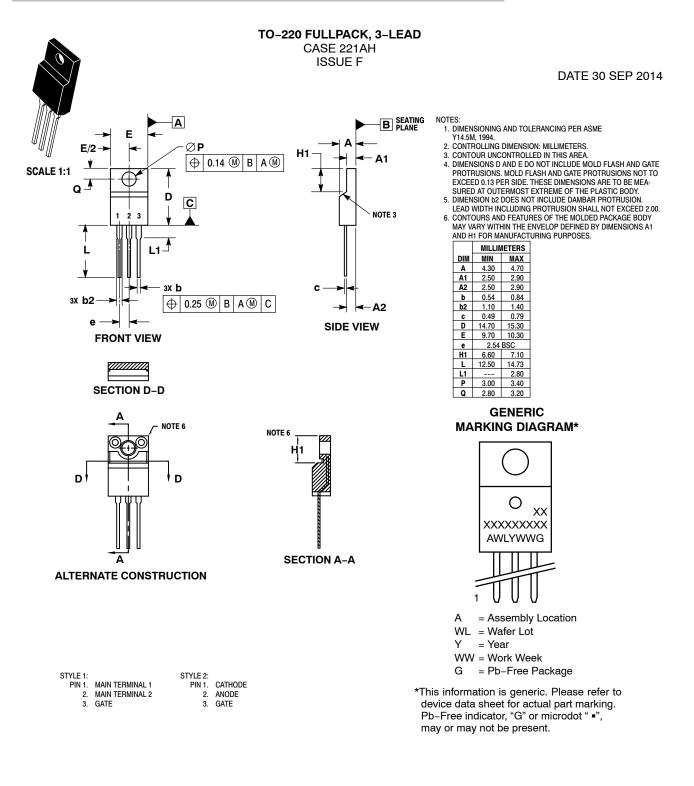
ORDERING INFORMATION

Device	Package	Shipping [†]
NTST40100CTG	TO-220AB (Pb-Free)	50 Units / Rail
NTSB40100CT-1G	SB40100CT-1G I ² PAK 50 Units / Rail (Pb-Free)	
NTSB40100CTG	D ² PAK (Pb-Free)	50 Units / Rail
NTSB40100CTT4G	D ² PAK (Pb-Free)	800 / Tape & Reel
NTSJ40100CTG	TO-220FP (Halide-Free)	50 Units / Rail

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



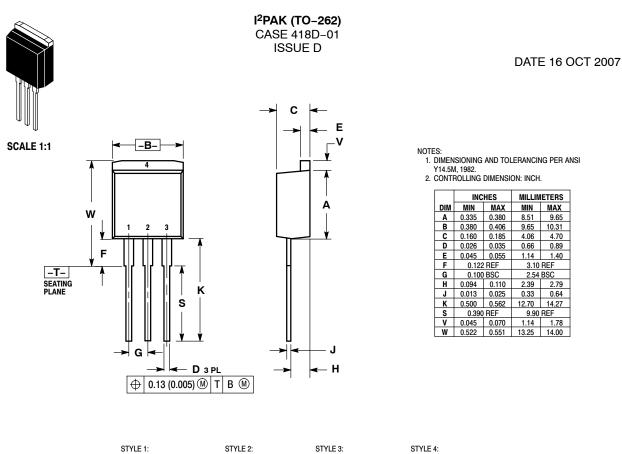




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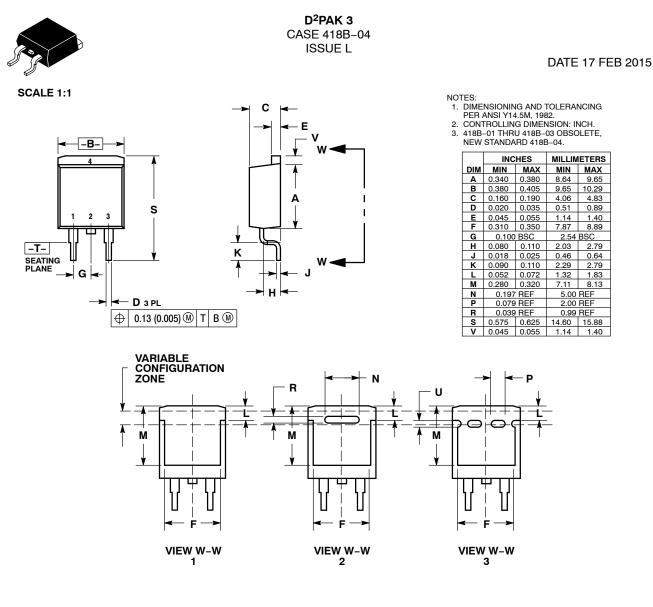


STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	GATE
2.	COLLECTOR	2.	DRAIN	2.	CATHODE	2.	COLLECTOR
3.	EMITTER	3.	SOURCE	3.	ANODE	3.	EMITTER
4.	COLLECTOR	4.	DRAIN	4.	CATHODE	4.	COLLECTOR

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STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. GATE	PIN 1. CATHODE	PIN 1. NO CONNECT
2. COLLECTOR	2. DRAIN	2. CATHODE	2. COLLECTOR	2. ANODE	2. CATHODE
3. EMITTER	SOURCE	ANODE	3. EMITTER	CATHODE	3. ANODE
4. COLLECTOR	4. DRAIN	CATHODE	4. COLLECTOR	4. ANODE	4. CATHODE

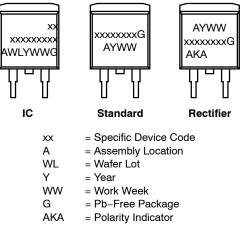
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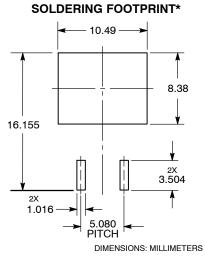
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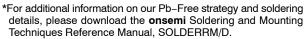
DATE 17 FEB 2015

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.





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